



Micro Commercial Components
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ER10A THRU ER10G

Features

- High Surge Capability
- Low Forward Voltage Drop
- High Current Capability
- Super Fast Switching Speed For High Efficiency

Maximum Ratings

- Operating Temperature: -55°C to +150°C
- Storage Temperature: -55°C to +150°C

MCC Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
ER10A	50V	35V	50V
ER10B	100V	70V	100V
ER10D	200V	140V	200V
ER10G	400V	280V	400V

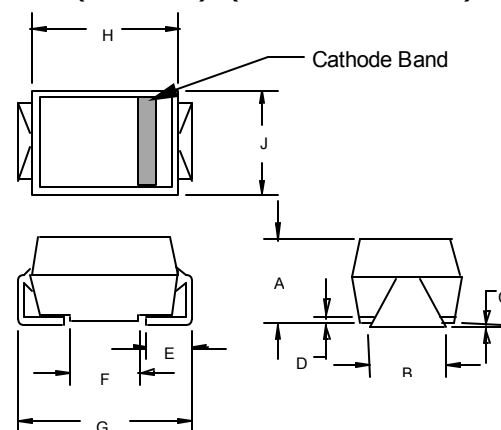
Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	10 A	$T_A = 55^\circ\text{C}$
Peak Forward Surge Current	I_{FSM}	200A	8.3ms, half sine
Maximum Instantaneous Forward Voltage	V_F	1.0V	$I_{FM} = 10.0\text{A};$ $T_A = 25^\circ\text{C}$
Maximum DC Reverse Current At Rated DC Blocking Voltage	I_R	10.0 μA	$T_A = 25^\circ\text{C}$
Maximum Reverse Recovery Time ER10A-ER10D ER10G	T_{rr}	35ns 60ns	$I_F=0.5\text{A}, I_R=1.0\text{A},$ $I_{rr}=0.25\text{A}$

*Pulse Test: Pulse Width 300 μsec , Duty Cycle 1%

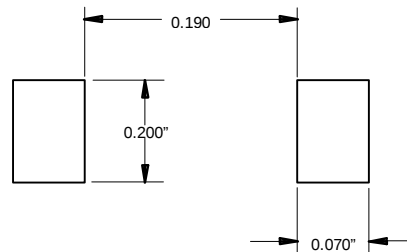
10 Amp Super Fast Recovery Rectifier 50 to 400 Volts

DO-214AB (SMCJ) (Round Lead)



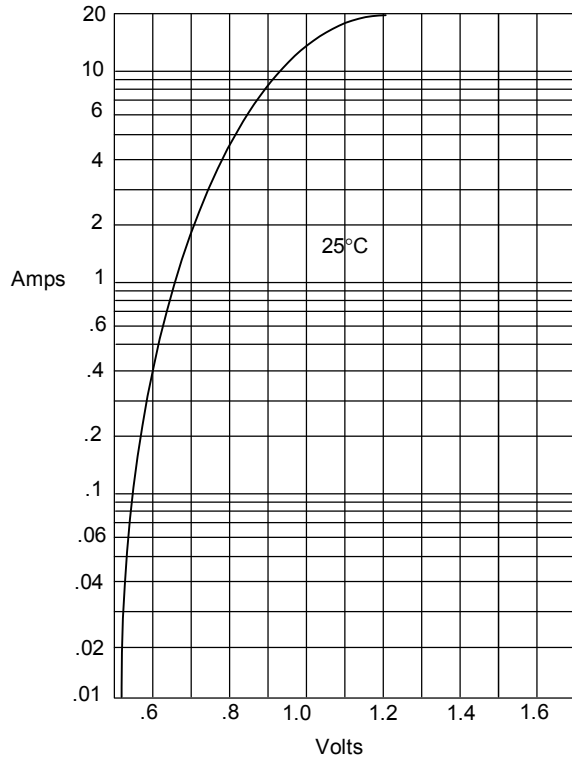
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.200	.214	5.08	5.43	
B	.177	.203	4.70	5.30	
C	.002	.005	.05	.13	
D	—	.02	—	.51	
E	.053	.067	1.35	1.70	
F	.168	.179	4.27	4.55	
G	.320	.330	8.13	8.38	
H	.239	.243	6.08	6.18	
J	.234	.240	5.95	6.10	

SUGGESTED SOLDER PAD LAYOUT



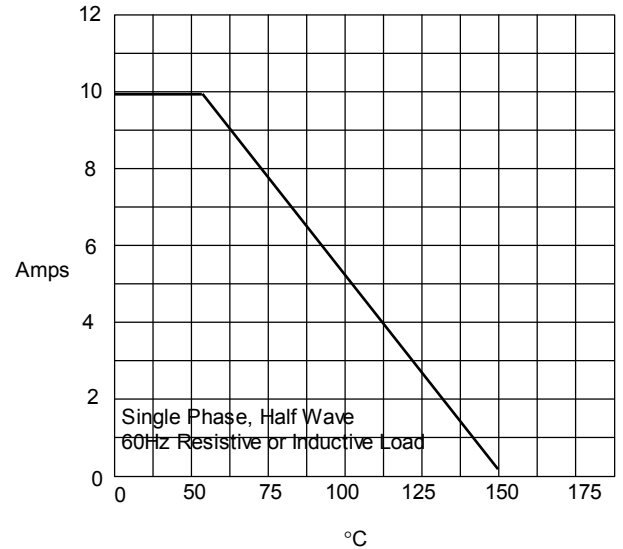
ER10A thru ER10G

Figure 1
Typical Forward Characteristics



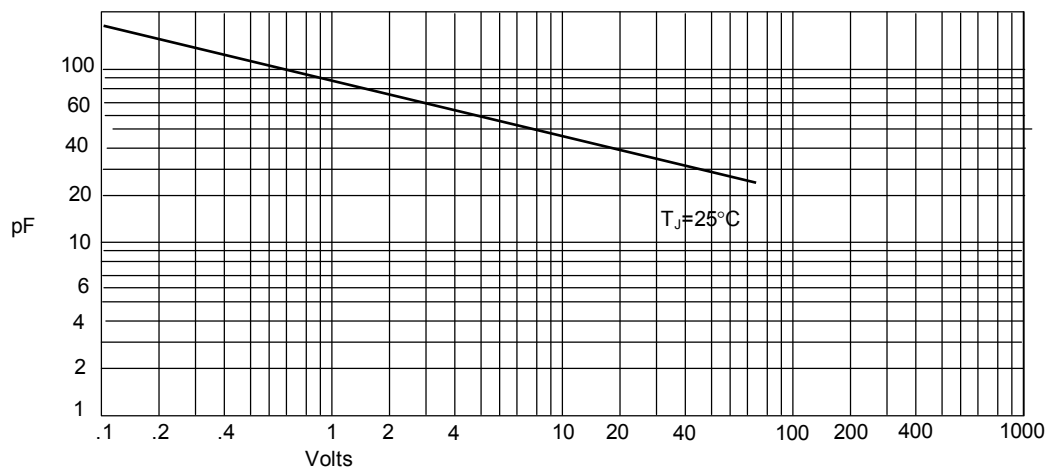
Instantaneous Forward Current - Amperes *versus*
Instantaneous Forward Voltage - Volts

Figure 2
Forward Derating Curve



Single Phase, Half Wave
60Hz Resistive or Inductive Load

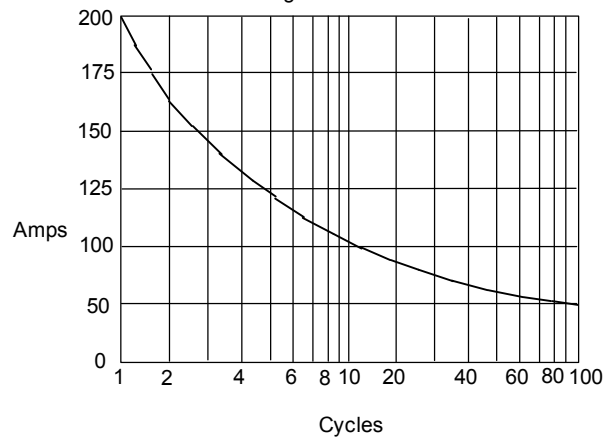
Figure 3
Junction Capacitance



Junction Capacitance - pF *versus*
Reverse Voltage - Volts

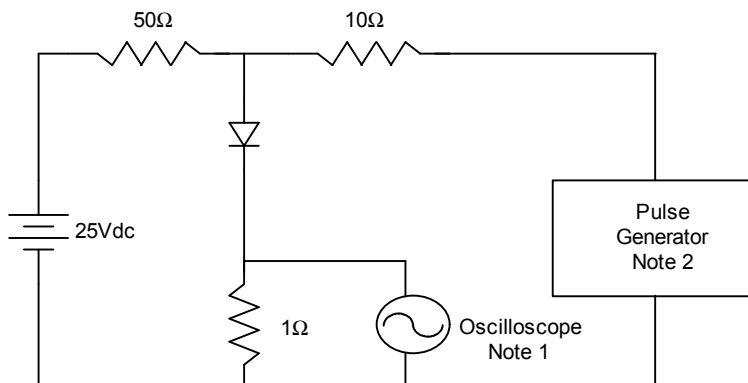
ER10A thru ER10G

Figure 4
Peak Forward Surge Current



Peak Forward Surge Current - Amperes *versus*
Number Of Cycles At 60Hz - Cycles

Figure 5
Reverse Recovery Time Characteristic And Test Circuit Diagram



- Notes:
1. Rise Time = 7ns max.
Input impedance = 1 megohm, 22pF
 2. Rise Time = 10ns max.
Source impedance = 50 ohms
 3. Resistors are non-inductive

